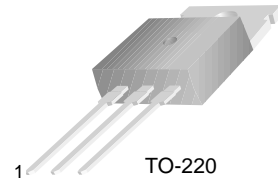


# TIP120/121/122

## Medium Power Linear Switching Applications

- Complementary to TIP125/126/127



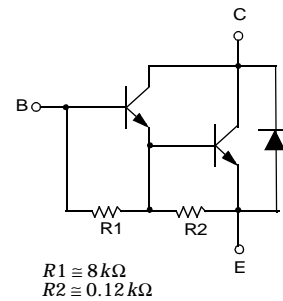
TO-220  
1.Base 2.Collector 3.Emmitter

## NPN Epitaxial Darlington Transistor

### Absolute Maximum Ratings $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage : TIP120	60	V
	: TIP121	80	V
	: TIP122	100	V
$V_{CEO}$	Collector-Emitter Voltage : TIP120	60	V
	: TIP121	80	V
	: TIP122	100	V
$V_{EBO}$	Emitter-Base Voltage	5	V
$I_C$	Collector Current (DC)	5	A
$I_{CP}$	Collector Current (Pulse)	8	A
$I_B$	Base Current (DC)	120	mA
$P_C$	Collector Dissipation ( $T_a=25^\circ\text{C}$ )	2	W
	Collector Dissipation ( $T_C=25^\circ\text{C}$ )	65	W
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{STG}$	Storage Temperature	- 65 ~ 150	$^\circ\text{C}$

Equivalent Circuit



### Electrical Characteristics $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
$V_{CEO(sus)}$	Collector-Emitter Sustaining Voltage	$I_C = 100\text{mA}, I_B = 0$	60		V
	: TIP120				
	: TIP121				
$I_{CEO}$	Collector Cut-off Current	$V_{CE} = 30\text{V}, I_B = 0$ $V_{CE} = 40\text{V}, I_B = 0$ $V_{CE} = 50\text{V}, I_B = 0$		0.5	mA
	: TIP120				
	: TIP121				
$I_{CBO}$	Collector Cut-off Current	$V_{CB} = 60\text{V}, I_E = 0$ $V_{CB} = 80\text{V}, I_E = 0$ $V_{CB} = 100\text{V}, I_E = 0$		0.2	mA
	: TIP120				
	: TIP121				
$I_{EBO}$	Emitter Cut-off Current	$V_{BE} = 5\text{V}, I_C = 0$		2	mA
$h_{FE}$	* DC Current Gain	$V_{CE} = 3\text{V}, I_C = 0.5\text{A}$ $V_{CE} = 3\text{V}, I_C = 3\text{A}$	1000		
$V_{CE(sat)}$	* Collector-Emitter Saturation Voltage	$I_C = 3\text{A}, I_B = 12\text{mA}$ $I_C = 5\text{A}, I_B = 20\text{mA}$		2.0	V
				4.0	V
$V_{BE(on)}$	* Base-Emitter ON Voltage	$V_{CE} = 3\text{V}, I_C = 3\text{A}$		2.5	V
$C_{ob}$	Output Capacitance	$V_{CB} = 10\text{V}, I_E = 0, f = 0.1\text{MHz}$		200	pF

\* Pulse Test :  $PW \leq 300\mu\text{s}$ , Duty cycle  $\leq 2\%$

# Typical characteristics

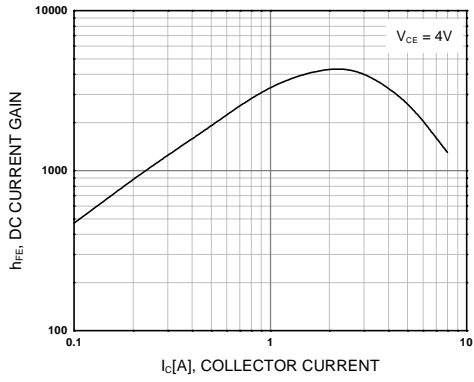


Figure 1. DC current Gain

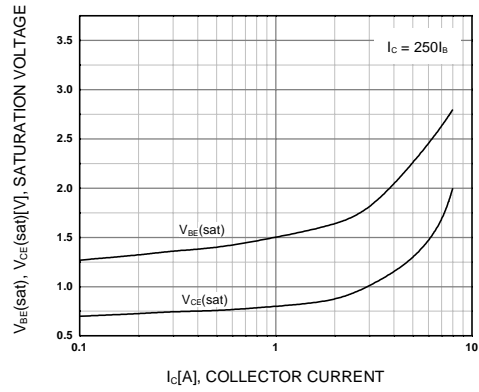


Figure 2. Base-Emitter Saturation Voltage  
Collector-Emitter Saturation Voltage

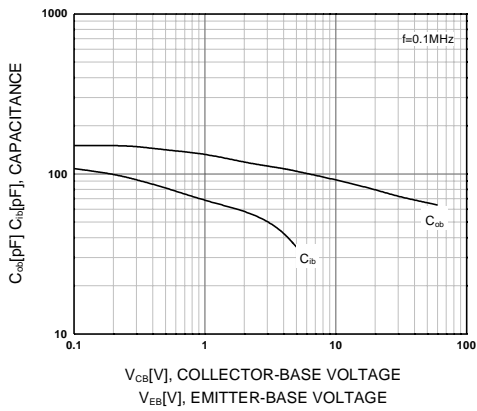


Figure 3. Output and Input Capacitance  
vs. Reverse Voltage

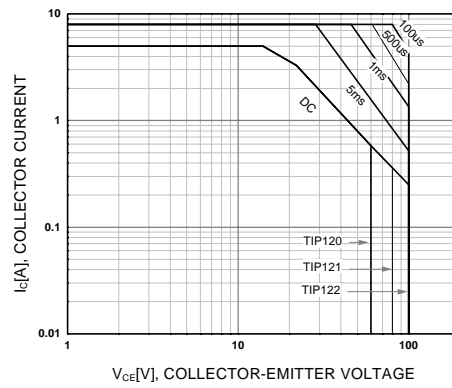


Figure 4. Safe Operating Area

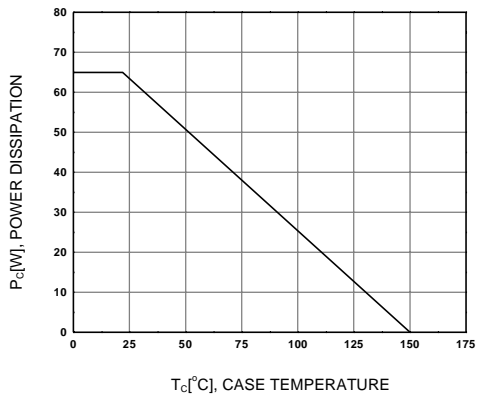
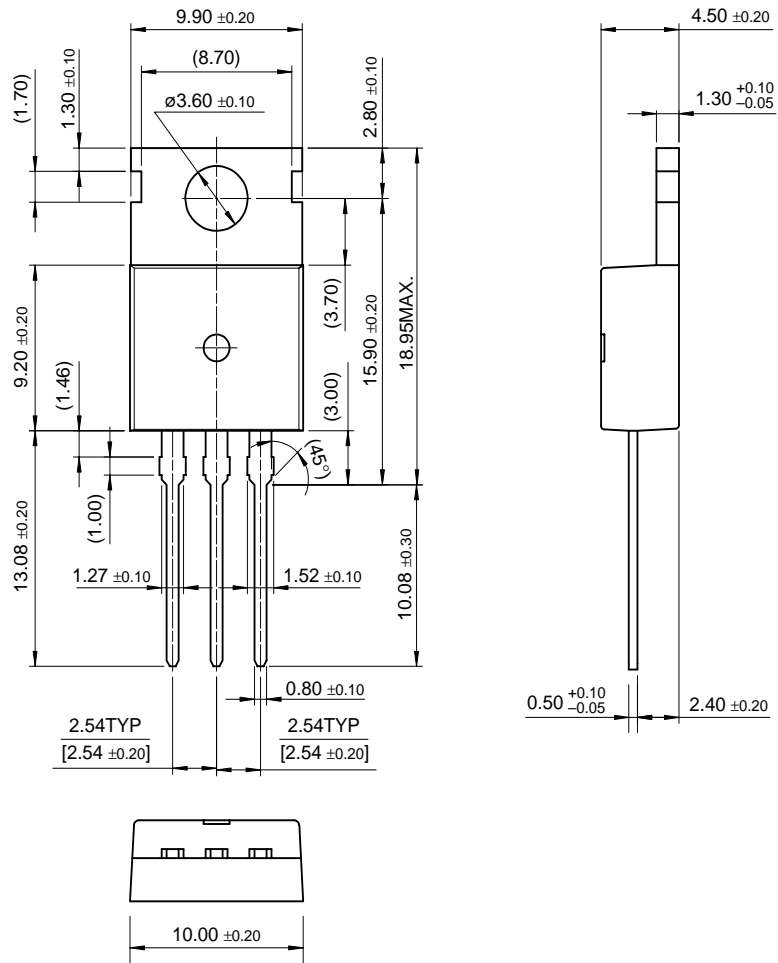


Figure 5. Power Derating

# Package Dimensions

## TO-220

TIP120/121/122



Dimensions in Millimeters

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EnSigna™	MicroFET™	Quiet Series™	UHC™
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